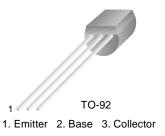


SEMICONDUCTOR®

KSC388

TV Final Picture IF Amplifier Applications

- G_{PE}= 33dB (TYP) at f=45MHz
 Suffix "-C" means Center Collector (1. Emitter 2. Collector 3. Base)



NPN Epitaxial Silicon Transistor

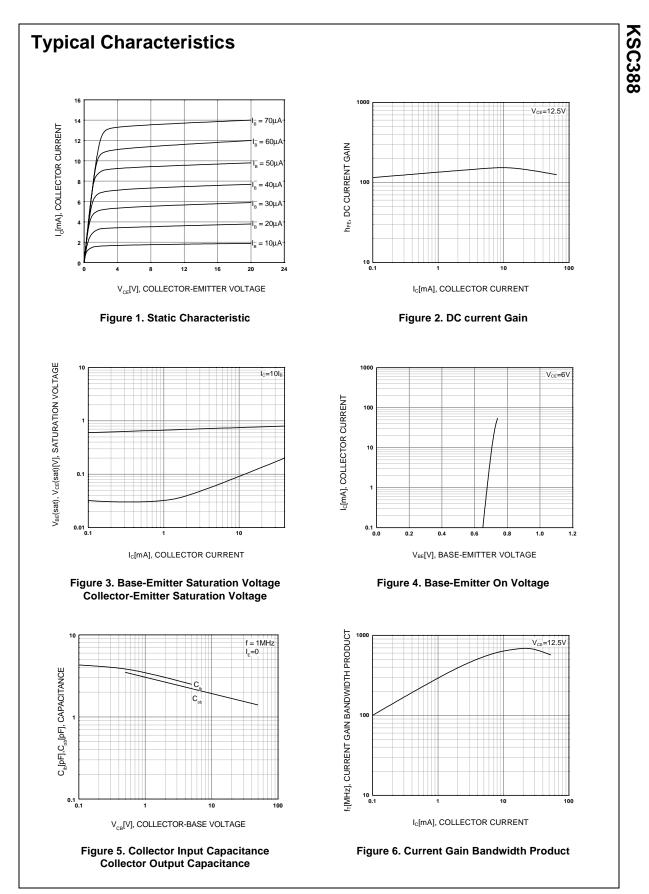
Absolute Maximum	Ratings $T_a=25^{\circ}C$ unless otherwise noted
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Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage	30	V	
V _{CEO}	Collector-Emitter Voltage	25	V	
V _{EBO}	Emitter-Base Voltage	4	V	
с	Collector Current	50	mA	
Pc	Collector Power Dissipation	300	mW	
Г _Ј	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	-55 ~ 150	°C	

Electrical Characteristics T_a=25°C unless otherwise noted

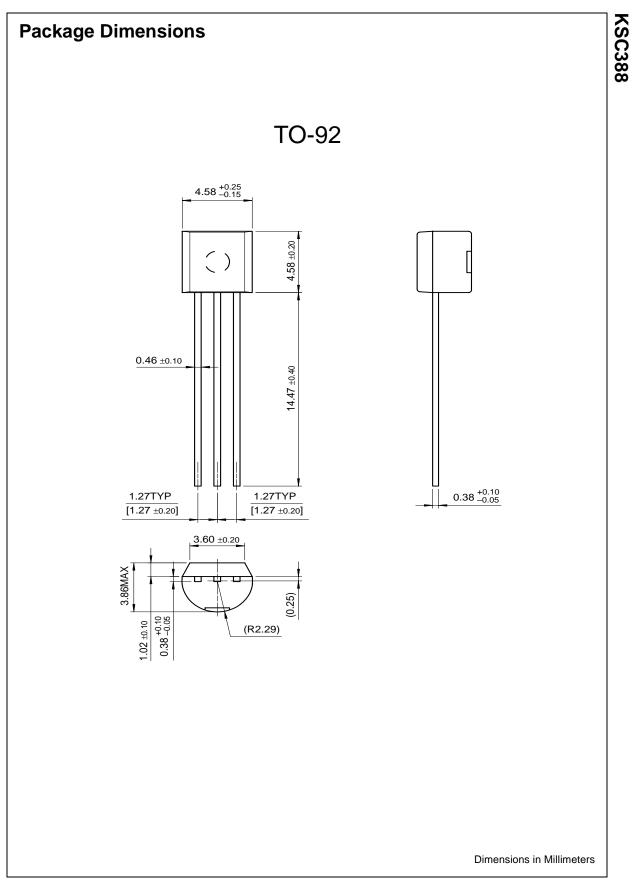
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =10μΑ, I _E =0	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0	25			V
I _{CBO}	Collector Cut-off Current	V _{CB} =30V, I _E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V _{EB} =3V, I _C =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =12.5V, I _C =12.5mA	20		200	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =15mA, I _B =1.5mA			0.2	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =15mA, I _B =1.5mA			1.5	V
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz	0.8		2	pF
C _{c•rbb} ′	Collector-Base Time Constant	V _{CB} =10V, I _C =1mA f=30MHz			25	ps
f _T	Current Gain Bandwidth Product	V _{CE} =12.5V, I _C =12.5mA 300				MHz
G _{PE}	Power Gain	V _{CC} =12.5V, I _C =12.5mA f=45MHz	28	33	36	dB

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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Definition of Terms

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.